Schottky Rectifier, 100 A

PowerTab™

FEATURES

- 150 °C T_J operation
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
- PowerTab™ package
- Lead (Pb)-free plating
- Compliant to RoHS directive 2002/95/EC

Pb-free
RoHS COMPLIANT

DESCRIPTION

The 100BGQ030 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies.
The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

PRODUCT SUMMARY	
$I_{F(AV)}$	100 A
V_F at 100 A at 25 °C	0.63 V
I_R at 125 °C	460 mA
V_R	30 V

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	100	A
	T_C	106	°C
V_{RRM}		30	V
I_{FSM}	t_p = 5 µs sine	4500	A
V_F	100 Apk (typical)	0.49	V
	T_J	150	°C
T_J	Range	- 55 to 150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	100BGQ030	UNITS
Maximum DC reverse voltage	V_R	30	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at T_C = 106 °C, rectangular waveform		100	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	4500	A
		10 ms sine or 6 ms rect. pulse		850	
Non-repetitive avalanche energy	E_{AS}	T_J = 25 °C, I_{AS} = 8 A, L = 1.12 mH		36	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		8	A

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop	V_{FM} (1)	50 A	T_J = 25 °C	0.47	0.5	V
		100 A		0.56	0.63	
		50 A	T_J = 150 °C	0.36	0.4	
		100 A		0.49	0.56	
Reverse leakage current	I_{RM} (1)	T_J = 125 °C, V_R = 15 V		80	160	mA
		T_J = 150 °C, V_R = 30 V		800	1100	
		T_J = 25 °C	V_R = Rated V_R	0.6	2.4	
		T_J = 125 °C		260	460	
Maximum junction capacitance	C_T	V_R = 5 V_{DC}, (test signal range 100 kHz to 1 MHz) 25 °C		3800		pF
Typical series inductance	L_S	Measured from tab to mounting plane		3.5		nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000		V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	0.50	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.30	
Approximate weight				5	g
				0.18	oz.
Mounting torque	minimum			1.2 (10)	N · m (lbf · in)
	maximum			2.4 (20)	
Marking device			Case style PowerTab™	100BGQ030	

For technical questions, contact: diodestech@vishay.com
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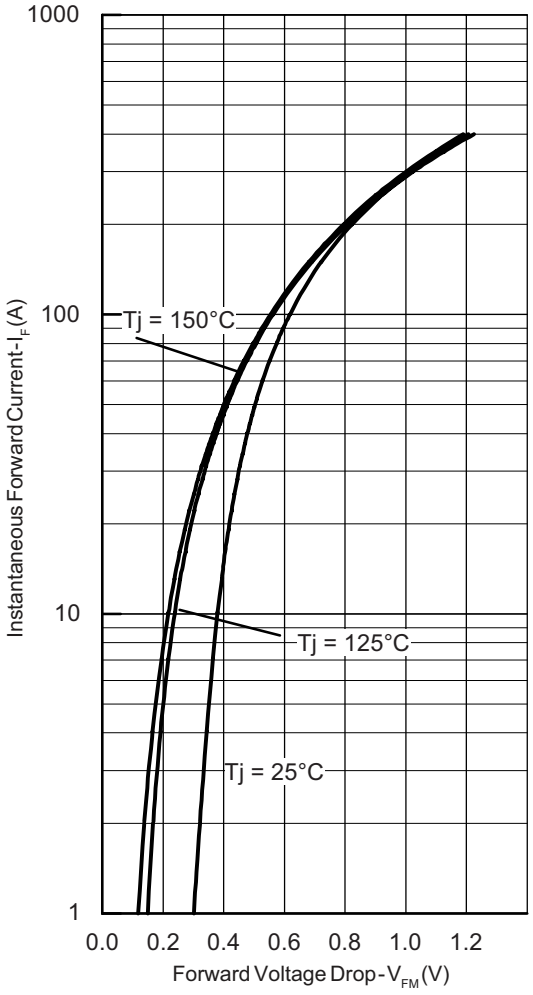


Fig. 1 - Maximum Forward Voltage Drop Characteristics

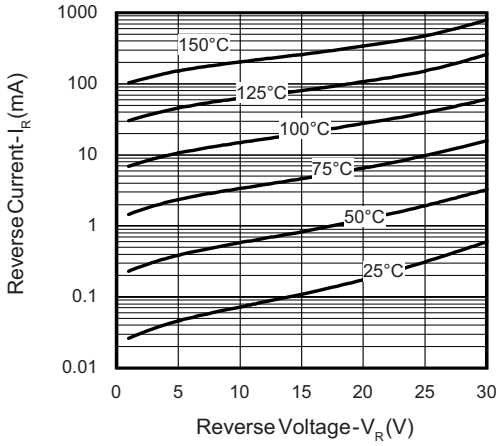


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

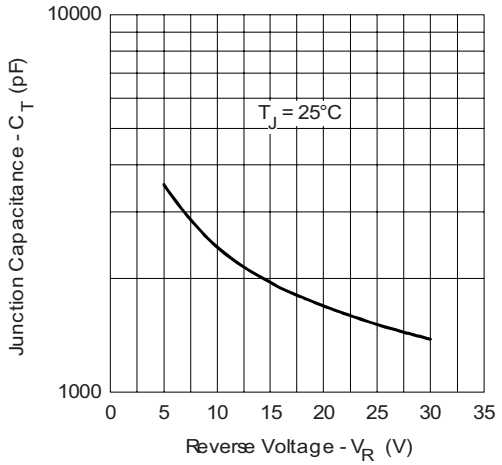


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

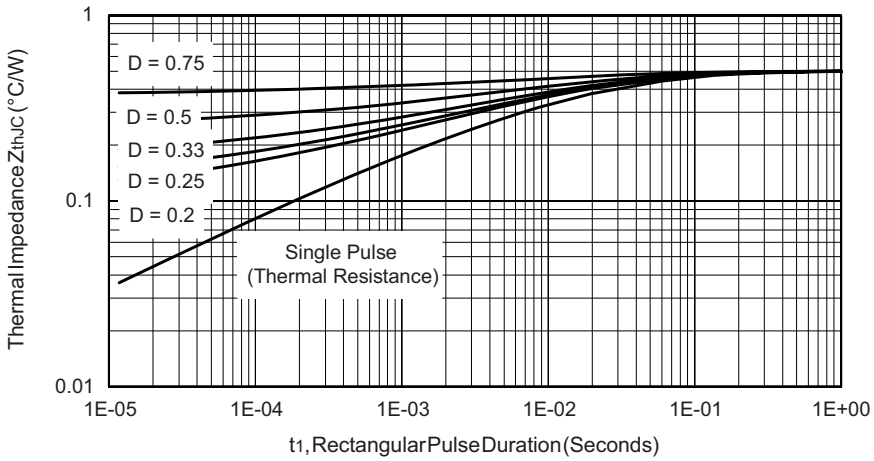


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

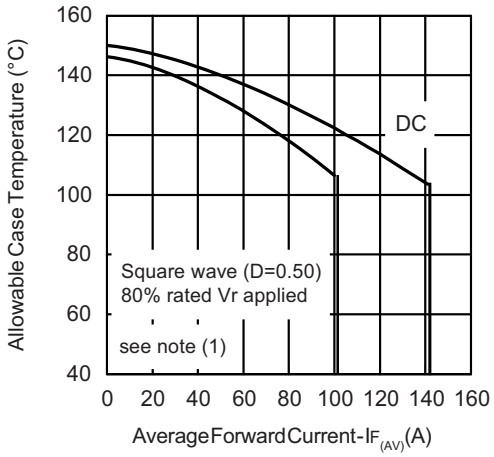


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

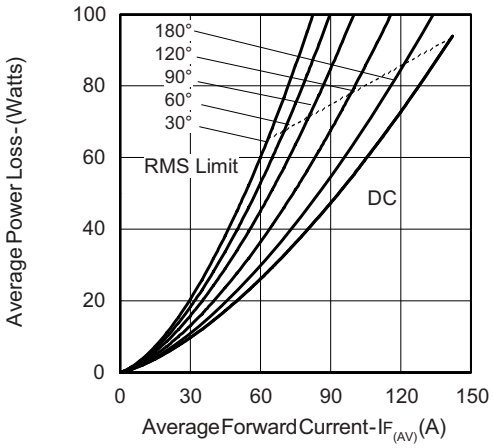


Fig. 6 - Forward Power Loss Characteristics

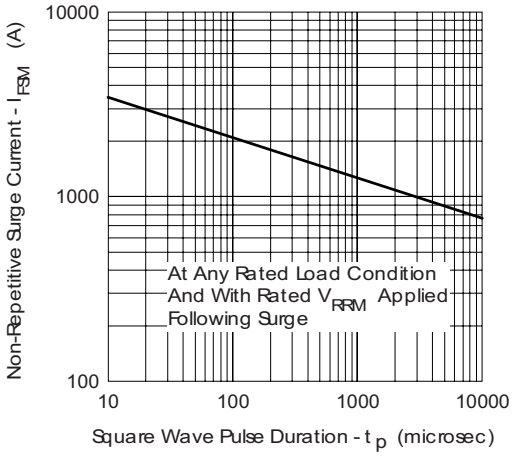


Fig. 7 - Maximum Non-Repetitive Surge Current

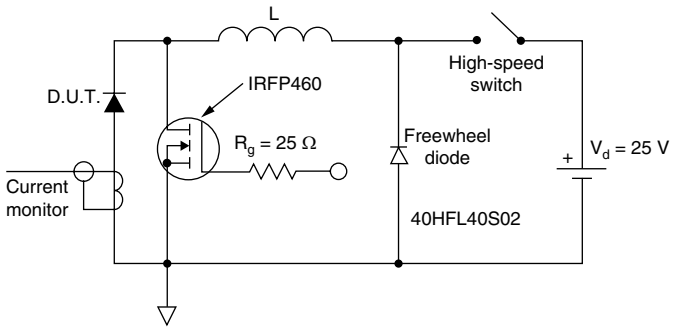


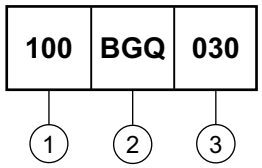
Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE

Device code



1 - Current rating
2 - Essential part number
3 - Voltage code = V_{RRM}

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95240
Part marking information	www.vishay.com/doc?95370
Application note	www.vishay.com/doc?95179

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